2SD1821, 2SD1821A

Silicon NPN epitaxial planar type

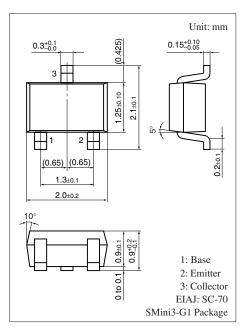
For high breakdown voltage low-frequency and low-noise amplification

■ Features

- ullet High collector-emitter voltage (Base open) V_{CEO}
- Low noise voltage NV
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SD1821	V_{CBO}	150	V
(Emitter open)	2SD1821A		185	
Collector-emitter voltage	2SD1821	V _{CEO}	150	V
(Base open)	2SD1821A		185	
Emitter-base voltage (Coll	$V_{\rm EBO}$	5	V	
Collector current	I_{C}	50	A	
Peak collector current	I_{CP}	100	A	
Collector power dissipation	P_{C}	150	mW	
Junction temperature	T_{j}	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	



Marking Symbol:

• 2SD1821: P • 2SD1821A: L

■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

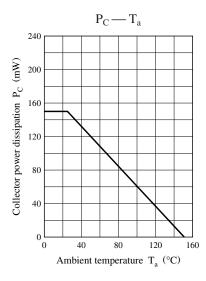
Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage	2SD1821	V _{CEO}	$I_C = 100 \mu\text{A}, I_B = 0$	150			V
(Base open)	2SD1821A			185			
Emitter-base voltage (Collector open)		V_{EBO}	$I_E = 10 \ \mu A, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)		I_{CBO}	$V_{CB} = 100 \text{ V}, I_{E} = 0$			1	μΑ
Forward current transfer ratio *		h _{FE}	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	130		330	_
Collector-emitter saturation voltage		V _{CE(sat)}	$I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$			1	V
Transition frequency		f_T	$V_{CB} = 10 \text{ V}, I_{E} = -10 \text{ mA}, f = 200 \text{ MHz}$		150		MHz
Collector output capacitance		C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		2.3		pF
(Common base, input open circuited)							
Noise voltage		NV	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}, G_{V} = 80 \text{ dB}$		150		mV
			$R_g = 100 \text{ k}\Omega$, Function = FLAT				

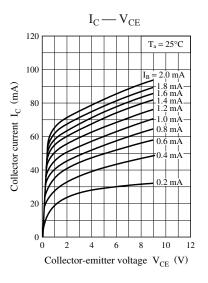
 $Note)\ 1.\ Measuring\ methods\ are\ based\ on\ JAPANESE\ INDUSTRIAL\ STANDARD\ JIS\ C\ 7030\ measuring\ methods\ for\ transistors.$

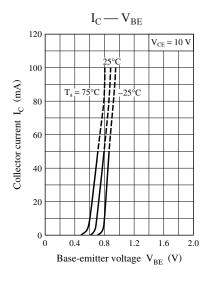
2. *: Rank classification

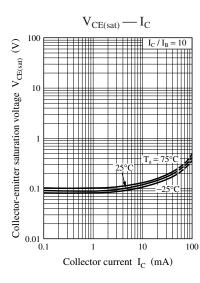
Rank	Q	R
h_{FE}	130 to 220	185 to 330

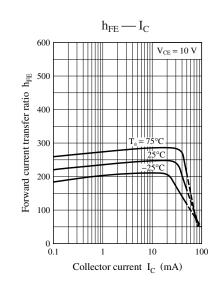
Panasonic

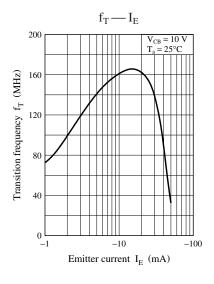


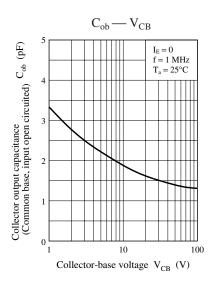












2 SJC00228CED

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